LM379

1

National Semiconductor

Audio/Radio Circuits

LM379 Dual 6 Watt Audio Amplifier

General Description

The LM379 is a monolithic dual power amplifier which offers high quality performance for stereo phonographs, tape players, recorders, and AM-FM stereo receivers, etc.

The LM379 will deliver 6W/channel to an 8 Ω load. The amplifier is designed to operate with a minimum of external components and contains an internal bias regulator to bias each amplifier. Device overload protection consists of both internal current limit and thermal shutdown. For more information, see AN-125.

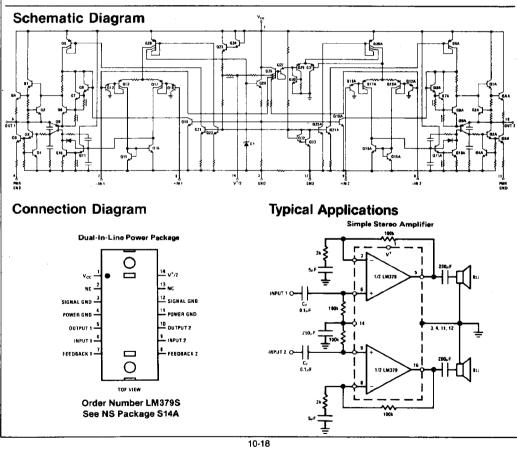
Features

- Avo typical 90 dB
- 6W per channel
- 70 dB ripple rejection
- 75 dB channel separation
- Internal stabilization
- Internal stabilization

- Self centered biasing
- 3 MΩ input impedance
- Internal current limiting
- Internal thermal protection

Applications

- Multi-channel audio systems
- Tape recorders and players
- Movie projectors
- Automotive systems
- Automotive systems
- Stereo phonographs
- Bridge output stages
- AM-FM radio receivers
- Intercoms
- Servo amplifiers
- Instrument systems



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Absolute Maximum Ratings

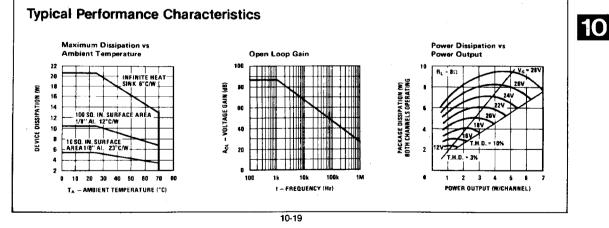
Supply Voltage	35V
Input Voltage	0V - VSUPPLY
Operating Temperature	0°C to +70°C
Storage Temperature	-65°C to +150°C
Junction Temperature	150°C
Lead Temperature (Soldering, 10 seconds)	300°C

Electrical Characteristics

 $V_{\rm S}$ = 28V, $T_{\rm TAB}$ = 25°C, $R_{\rm L}$ = 8 Ω , $A_{\rm V}$ = 50 (34 dB), unless otherwise specified.

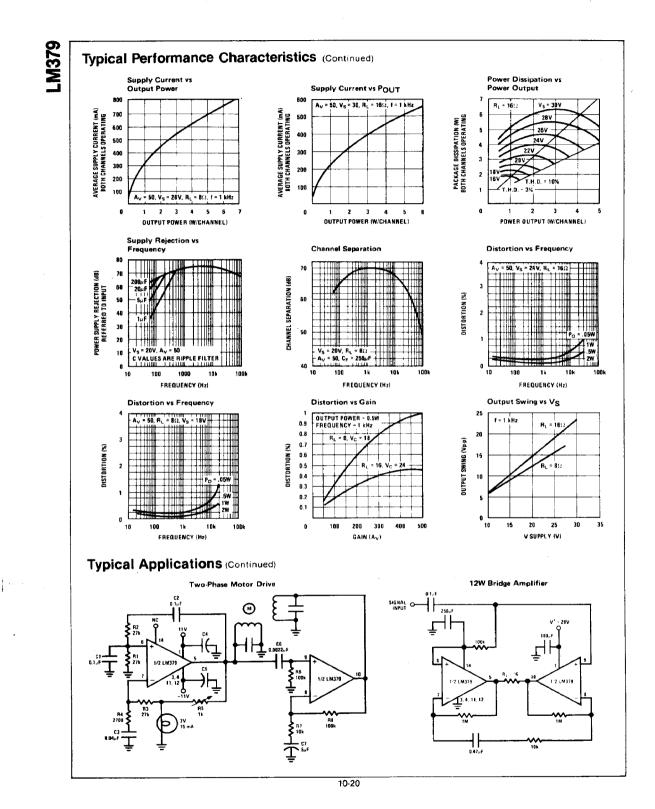
PARAMETER	CONDITIONS	MIN	ТҮР	MAX	UNITS
Total Supply Current	P _{OUT} = 0W P _{OUT} = 1.5W/Channel		15 430	65	mA ṁA
DC Output Level		1	14		v
Supply Voltage		10		· /	v
Output Power	T.H.D. = 5% T.H.D. = 10%	6	6 7		w W
T.H.D.	P _{OUT} = 1W/Channel, f = 1 kHz P _{OUT} = 4W/Channel, f − 1 kHz		0.07 0.2	1	% %
Offset Voltage		ł	15	<u>ا</u> ا	mV
Input Bias Current		1	100	i I	nA
Input Impedance		3			MΩ
Open Loop Gain	R _s = 0Ω	66	90	'	dB
Channel Separation	C _F = 250µF, f = 1 kHz	50	70	1	dB
Ripple Rejection	f = 120 Hz, C _F = 250µF	1	70	1	dB
Current Limit		1	1.5	1	A
Slew Rate		i	1.4	}	V/µs
Equivalent Input Noise Voltage	B _S = 600Ω, 100 Hz – 10 kHz	l l	3	1	μVrms

Note 1: For operation at ambient temperatures greater than 25°C the LM379 must be derated based on a maximum 150°C junction temperature using a thermal resistance which depends upon device mounting techniques. In most applications it is advisable to heat sink to the chassis. See curves.

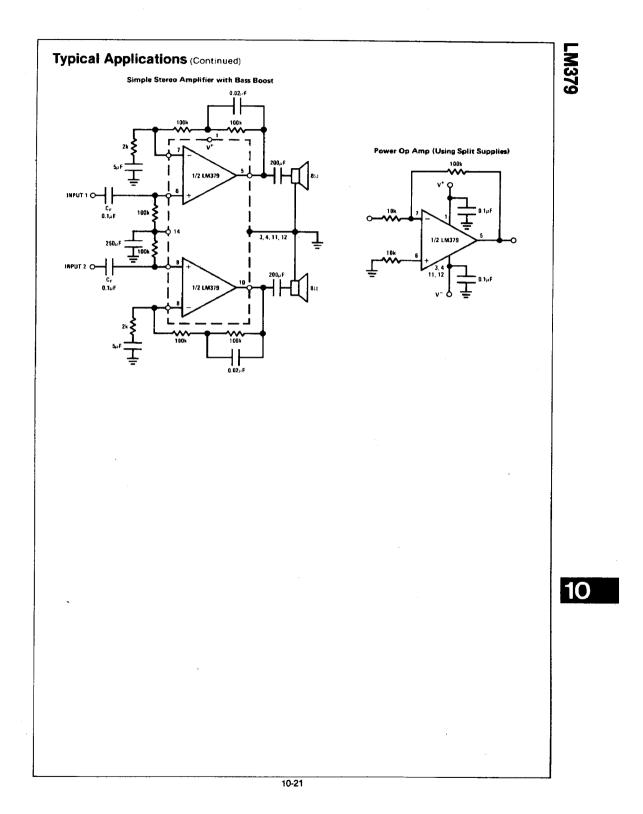


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